TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP180

Telephone Use Equipment Programmable Controllers AC/DC-Input Module Telecommunication

The TOSHIBA mini flat coupler TLP180 is a small outline coupler, suitable for surface mount assembly.

TLP180 consist of a photo transistor, optically coupled to a gallium arsenide infrared emitting diode connected inverse parallel, and can operate directly by AC input current.

Collector-emitter voltage: 80 V (min)

• Current transfer ratio: 50% (min)

Rank GB: 100% (min)

Isolation voltage: 3750 Vrms (min)

UL recognized: UL1577, file No. E67349

· c-UL approved :CSA Component Acceptance Service

No. 5A, File No.E67349

Option (V4) type

VDE approved: EN60747-5-5

Maximum Operating Insuration Voltage: 565 Vpk

Highest Permissible Overvoltage: 6000 Vpk

Note: When a EN60747-5-5 approved type is needed, Please designate "Option(V4)"

Current Transfer Ratio

Classi- fication (Note 1)		Ratio (%) (I _C /I _F) = 5 V, Ta = 25°C Max	Marking Of Classification		
Standard	50	600	Blank, YE, GR, BL, GB		
Rank Y	50	150	YE		
Rank GR	100	300	GR		
Rank BL	200	<i>∕</i> 600	BL		
Rank GB	100	600	GB, GR, BL		

Note: The product with the Rank Y and BL are limited in production.

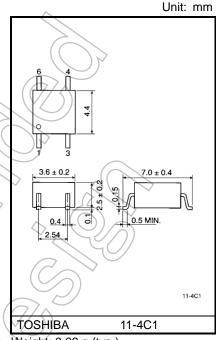
For details, please contact your nearest Toshiba sales representative.

Note 1: Ex. rank GB: TLP180 (GB)

Note: Application type name for certification test,

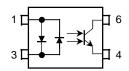
please use standard product type name, i.e.

TLP180(GB): TLP180



Weight: 0.09 g (typ.)

Pin Configuration (top view)



- 1: Anode, Cathode
- 3: Cathode, Anode
- 4: Emitter
- 6: Collector

Start of commercial production 1995-12



Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	I _{F(RMS)}	±50	mA
	Forward current detating (Ta ≥ 53°C)	ΔIF/°C	-0.7	mA/°C
	Pulse forward current (Note 1)	IFP	±1	A
凹	Diode power dissipation	PD	100	mW
	Diode power dissipation derating (Ta ≥ 53°C)	ΔP _D /°C	-1.39	mW/°C
	Junction temperature	Tj	125	°C
	Collector-emitter voltage	VCEO	80)) v
	Emitter-collector voltage	VECO	7	V
Detector	Collector current	Ic	50	mA
Dete	Power dissipation	PC	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP _C /°C	-1.5	mW/°C
	Junction temperature	Tj (125	°C
Stor	rage temperature range	T _{stg}	-55 to 125	(O°C
Ope	erating temperature range	Topr	-55 to 100	
Lead soldering temperature (10 s)		Tsol	260	°C
Total package power dissipation		R	200	mW
Total package power dissipation derating (Ta ≥ 25°C)		ΔPT/°C	-2.0	mW/°C
Isola	ation voltage (AC, 60 s, R.H. ≤ 60%) (Note 2)	BVs	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width $\leq 100 \,\mu s$, $f = 100 \,Hz$

Note 2: Device considered a two terminal device: Pins 1 and 3 shorted together and 4 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	48	V
Forward current	F(RMS)	_	16	20	mA
Collector current	lc	_	1	10	mA
Operating temperature	Topr	-25	1	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

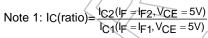
	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Ω	Forward voltage	VF	IF = ±10 mA	1.0	1.15	1.3	V
쁘	Capacitance	Ст	V = 0 V, f = 1 MHz	_	60	_	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	80	-	_	V
'n	Emitter-collector breakdown voltage	V(BR)ECO	I _E = 0.1 mA	(Z)>	_	V
Detector	Collector dark current	lana	VCE = 48 V (ambient light below 1000 &x) (Note 1)	7 ₉	0.01 (2)	0.1 (10)	μА
Collector dark current	ICEO	VCE = 48 V, Ta = 85°C (ambient light below 1000 &x) (Note 1))	2 (4)	50 (50)	μΑ	
	Capacitance (collector to emitter)	C _{CE}	V = 0 V, f = 1 MHz	_	10	_	pF

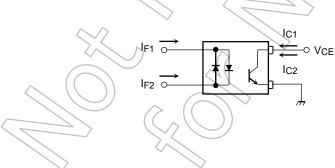
Note 1: Please use standard electric lamp to light up the device's marking surface.

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	Ic/IF	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	50)	_	600	. %
	IC/IF	Rank GB	100	_	600	70
Saturated CTR	I _C /I _{F(sat)}	$IF = \pm 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$) —	60	_	%
	iC/iF(sat)	Rank GB	30	_		/0
		IC = 2.4 mA, IF = ±8 mA		_	0.4	
Collector-emitter saturation voltage	VCE (sat)	I _C = 0.2 mA, I _F = ±1 mA		0.2		V
January Voltage	7	Rank GB		_	0.4	
Off-state collector current	IC(off)	$V_F = \pm 0.7 V$, $V_{CE} = 48 V$	_	1	10	μΑ
CTR symmetry	IC(ratio)	Ic (IF = -5 mA)/Ic (IF = 5 mA) (Note 1)	0.33	1	3	

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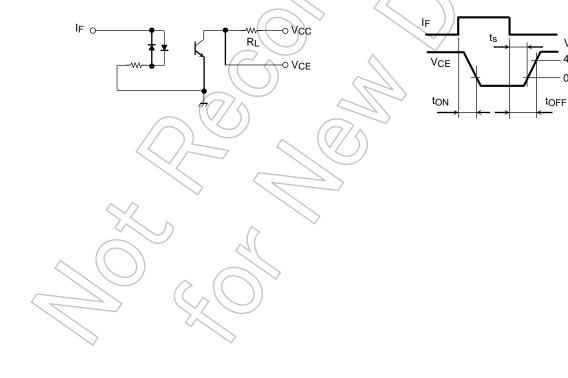
Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	Vs = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	Vs = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	-	Ω
		AC, 60 s	3750	_	_	\/
Isolation voltage	BVs	AC, 1 s, in oil		10000	_	V _{rms}
		DC, 60 s, in oil	1	10000	-	V _{dc}

Switching Characteristics (Ta = 25°C)

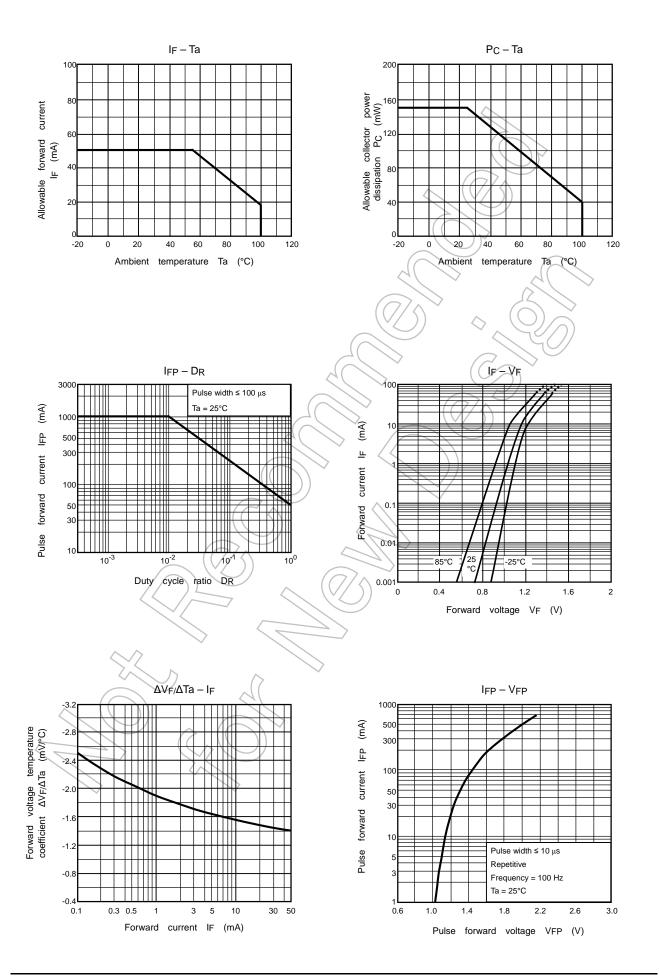
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t _r	4(>	_	2	\rightarrow	
Fall time	t _f	V _{CC} = 10 V, I _C = 2 mA	- (3	> _	0
Turn-on time	toN	$R_L = 100 \Omega$	-(0))3	_	μS
Turn-off time	toff			3/	_	
Turn-on time	toN			2	_	
Storage time	ts	$R_L = 1.9 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V}, I_F = \pm 16 \text{ mA}$	/9)	25	_	μS
Turn-off time	toff)	40	_	

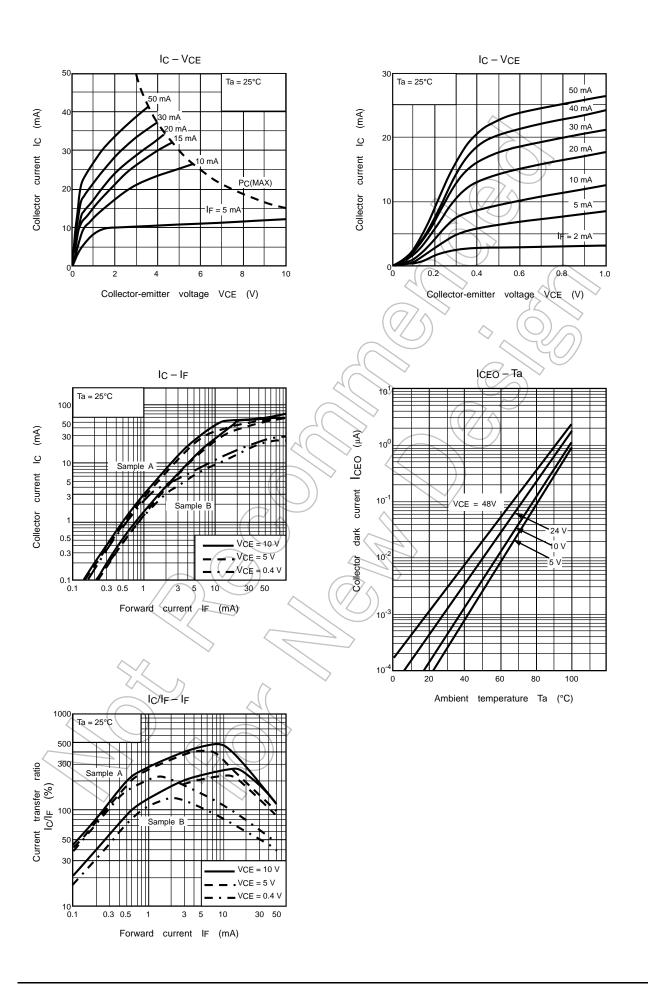
Fig. 1: Switching time test circuit



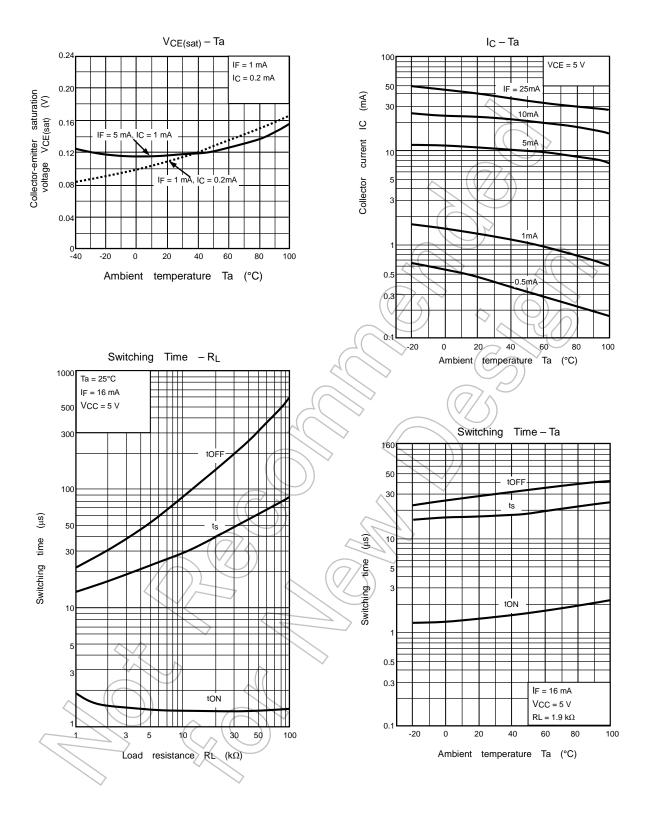
V_CC 4.5V

0.5V





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